# **Medium Power Transistor** (Motor, Relay drive) (60±10V, 2A) 2SD2212 / 2SD2143 / 2SD1866

#### Features

- 1) Built-in zener diode between collector and base.
- 2) Strong protection against reverse surges due to "L" loads.
- 3) Built-in resistor between base and emitter.
- 4) Built-in damper diode.

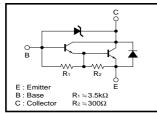
Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	60±10	V	
Collector-emitter voltage		Vceo	60±10	V	
Emitter-base voltage		Vebo	6	V	
Collector current		lc	2	A (DC)	
		ic	3 *1	A (Pulse)	
Collector power dissipation	2SD2212		0.5	w	
			2 *2		
	2SD2143	Pc	1	W	
			10	W (Tc=25°C)	
	2SD1866		1 * <sup>3</sup>	W	
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	°C	

\*1 Single pulse Pw=100ms
\*2 When mounted on a 40×40×0.7mm ceramic board.
\*3 Printed circuit board 1.7mm thick, collector plating 1cm<sup>2</sup> or larger

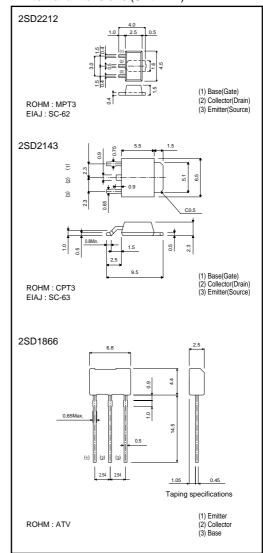
#### Packaging specifications and hFE

Туре	2SD2212	2SD2143	2SD1866
Package	MPT3	CPT3	ATV
hfe	1k to 10k	1k to 10k	1k to 10k
Marking	DR	-	-
Code	T100	TL	TV2
Basic ordering unit (pieces)	1000	2500	2500

#### Equivalent circuit



#### •External dimensions (Unit : mm)



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### 2SD2212 / 2SD2143 / 2SD1866

### Transistors

#### •Electrical characteristics (Ta=25°C)

	-					
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	50	-	70	V	Ic=50μA
Collector-emitter breakdown voltage	BVCEO	50	-	70	V	Ic=5mA
Collector cutoff current	Ісво	-	-	1.0	μA	Vcb=40V
Emitter cutoff current	ЕВО	-	-	3	mA	Veb=5V
Collector-emitter saturation voltage	VCE(sat)	-	-	1.5	V	Ic/IB=1A/1mA *
DC current transfer ratio	hfe	1000	-	10000	-	Vce=2V, Ic=1A
Transition frequency	f⊤	-	80	-	MHz	Vce=5V, Ie= -0.1A, f=30MHz
Output capacitance	Cob	-	25	-	pF	Vcb=10V, IE=0A, f=1MHz

\* Measured using pulse current.

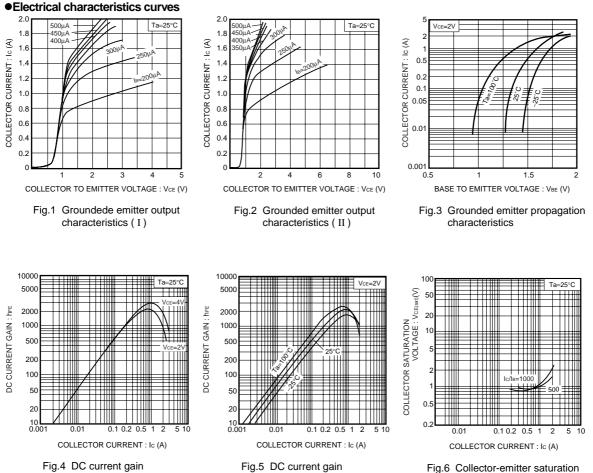


Fig.6 Collector-emitter saturation voltage vs. collector current

vs. collector current (I)

vs. collector current (II)

#### Transistors

#### 100 Ic/Is=1000 COLLECTOR SATURATION VOLTAGE : Vce(sat)(V) 50 20 10 5 2 1 00 0.5 0.2 0.01 0.10.2 0.5 1 2 5 10 COLLECTOR CURRENT : Ic (A)

Fig.7 Collector-emitter saturation voltage vs. collector current

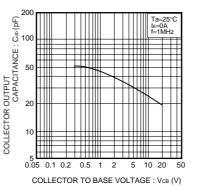


Fig.8 Collector output capacitance vs. collector-base voltage

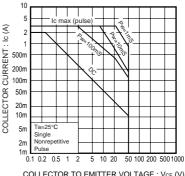


Fig.9 Safe operating area (A. S. O) 2SD2212 (MPT)

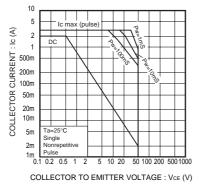
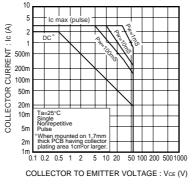
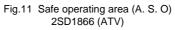


Fig.10 Safe operating area (A. S. O) 2SD2143 (CPT)





COLLECTOR TO EMITTER VOLTAGE : VCE (V)



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